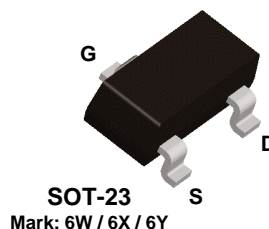
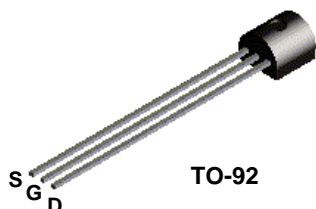


J174
J175
J176
J177

MMBFJ175
MMBFJ176
MMBFJ177



P-Channel Switch

This device is designed for low level analog switching sample and hold circuits and chopper stabilized amplifiers. Sourced from Process 88.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------------------------------|--|-------------|-------|
| V _{DG} | Drain-Gate Voltage | - 30 | V |
| V _{GS} | Gate-Source Voltage | 30 | V |
| I _{GF} | Forward Gate Current | 50 | mA |
| T _J , T _{stg} | Operating and Storage Junction Temperature Range | -55 to +150 | °C |

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

| Symbol | Characteristic | Max | | Units |
|------------------|---|-------------|-----------|-------|
| | | J174 - J177 | *MMBFJ175 | |
| P _D | Total Device Dissipation | 350 | 225 | mW |
| | Derate above 25°C | 2.8 | 1.8 | mW/°C |
| R _{θJC} | Thermal Resistance, Junction to Case | 125 | | °C/W |
| R _{θJA} | Thermal Resistance, Junction to Ambient | 357 | 556 | °C/W |

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

P-Channel Switch

(continued)

Electrical Characteristics

TA = 25°C unless otherwise noted

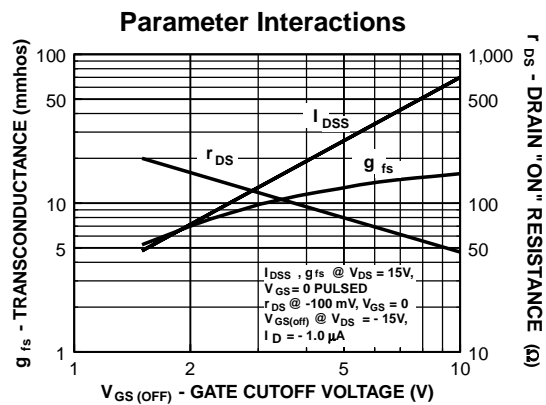
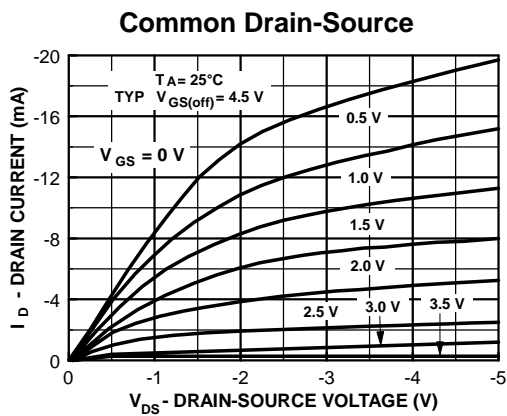
| Symbol | Parameter | Test Conditions | Min | Max | Units | |
|----------------------------|-------------------------------|--------------------------------|-------------|-----|-------|---|
| OFF CHARACTERISTICS | | | | | | |
| $B_{(BR)GSS}$ | Gate-Source Breakdown Voltage | $I_G = 1.0 \mu A, V_{DS} = 0$ | 30 | | V | |
| I_{GSS} | Gate Reverse Current | $V_{GS} = 20 V, V_{DS} = 0$ | | 1.0 | nA | |
| $V_{GS(off)}$ | Gate-Source Cutoff Voltage | $V_{DS} = -15 V, I_D = -10 nA$ | J174 | 5.0 | 10 | V |
| | | | J175 | 3.0 | 6.0 | V |
| | | | J176 | 1.0 | 4.0 | V |
| | | | J177 | 0.8 | 2.5 | V |

ON CHARACTERISTICS

| | | | | | | |
|--------------|----------------------------------|---------------------------------|-------------|------|------|----------|
| I_{DSS} | Zero-Gate Voltage Drain Current* | $V_{DS} = -15 V, V_{GS} = 0$ | J174 | -20 | -100 | mA |
| | | | J175 | -7.0 | -60 | mA |
| | | | J176 | -2.0 | -25 | mA |
| | | | J177 | -1.5 | -20 | mA |
| $r_{DS(on)}$ | Drain-Source On Resistance | $V_{DS} \leq 0.1 V, V_{GS} = 0$ | J174 | | 85 | Ω |
| | | | J175 | | 125 | Ω |
| | | | J176 | | 250 | Ω |
| | | | J177 | | 300 | Ω |

*Pulse Test: Pulse Width $\leq 300 \mu s$, Duty Cycle $\leq 2.0\%$

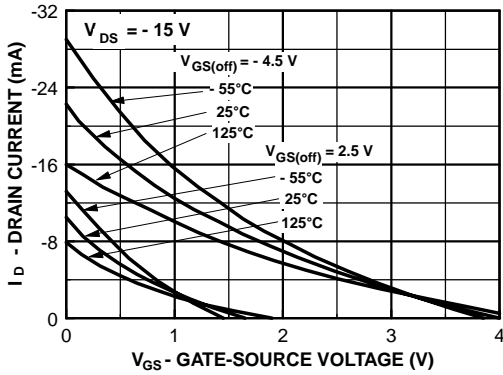
Typical Characteristics



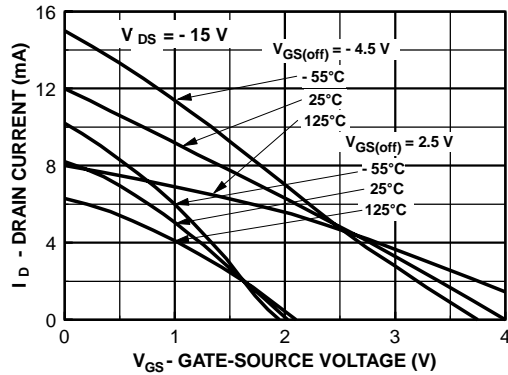
J174 / J175 / J176 / J177 / MMBFJ175 / MMBFJ176 / MMBFJ177

Typical Characteristics (continued)

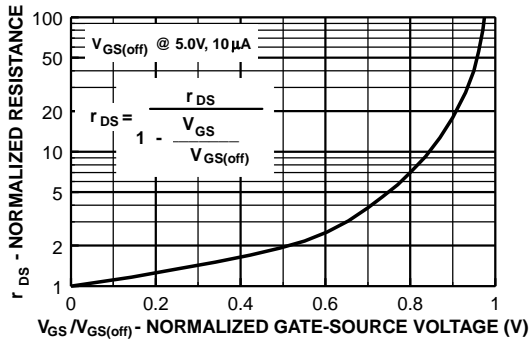
Transfer Characteristics



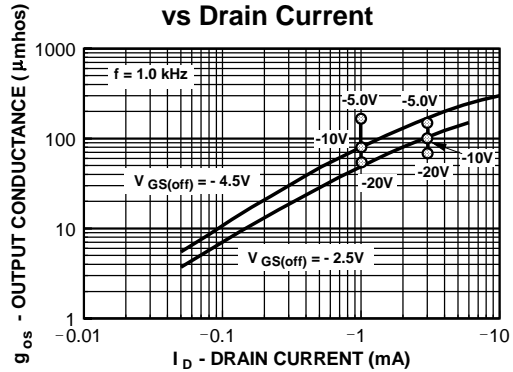
Transfer Characteristics



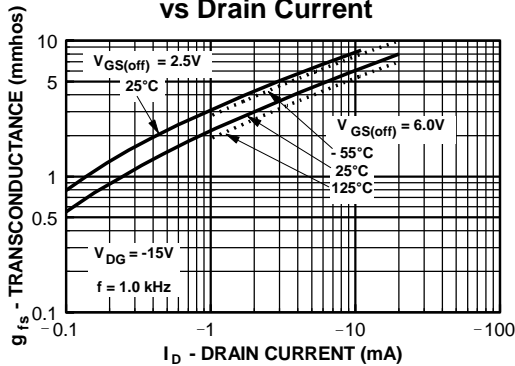
Normalized Drain Resistance vs Bias Voltage



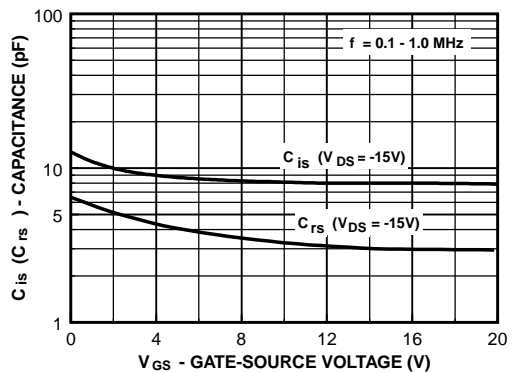
Output Conductance vs Drain Current



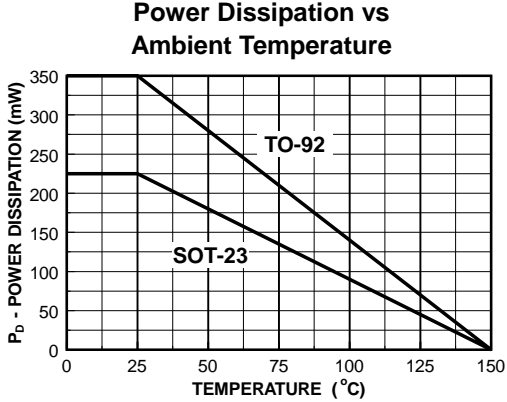
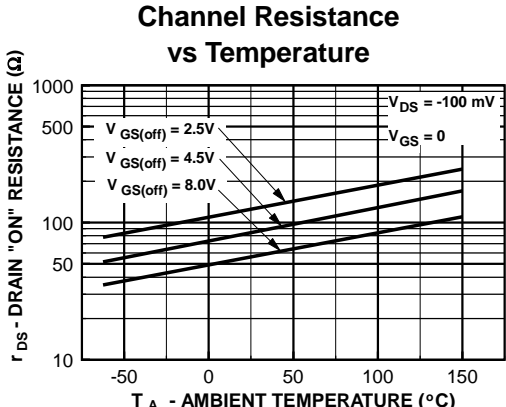
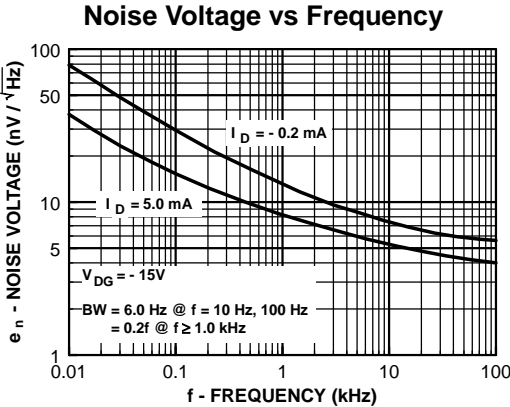
Transconductance vs Drain Current



Capacitance vs Voltage



Typical Characteristics (continued)



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|--------------------------|------------------------|---|
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